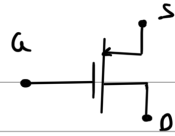
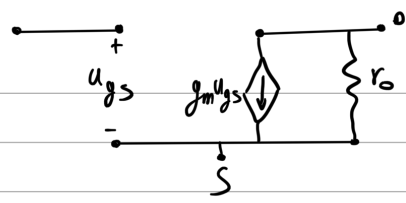


NMOS



PMOS



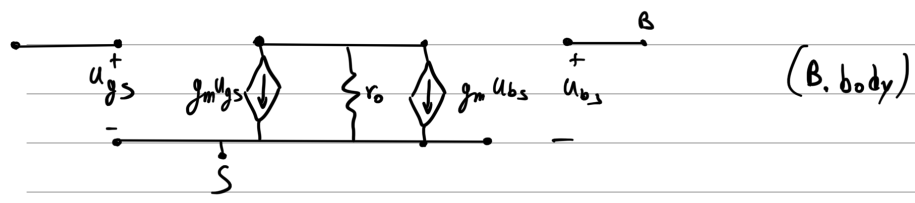
$$r_o = \frac{V_A}{I_D}, \quad V_A = \frac{1}{\lambda}, \quad I_D = \frac{1}{2} \mu_n C_{ox} \left(\frac{W}{L} \right) (V_{GS} - V_t)^2$$

$\underbrace{\mu_n C_{ox} \left(\frac{W}{L} \right)}_{k_n'} \underbrace{(V_{GS} - V_t)^2}_{V_{ov}}$
 $\underbrace{\quad\quad\quad}_{k_n}$

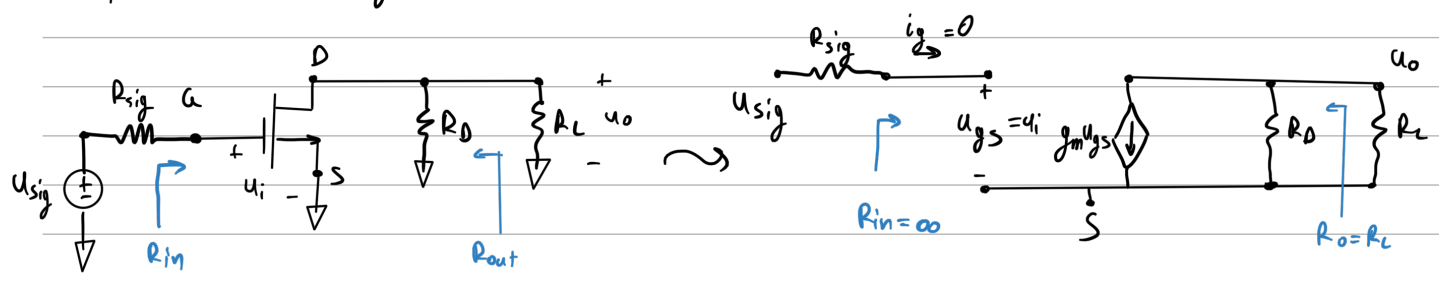
for PMOS: $|V_A|, |\lambda|, |V_{ov}|, |V_t|$

$$g_m \equiv \left. \frac{\partial i_D}{\partial u_{GS}} \right|_{u_{GS}=V_{GS}}$$

$$g_m = k_n V_{ov} = \mu_n C_{ox} \left(\frac{W}{L} \right) (V_{GS} - V_t) = \frac{2 I_D}{V_{ov}} = \sqrt{2 \mu_n C_{ox} \left(\frac{W}{L} \right) I_D}$$

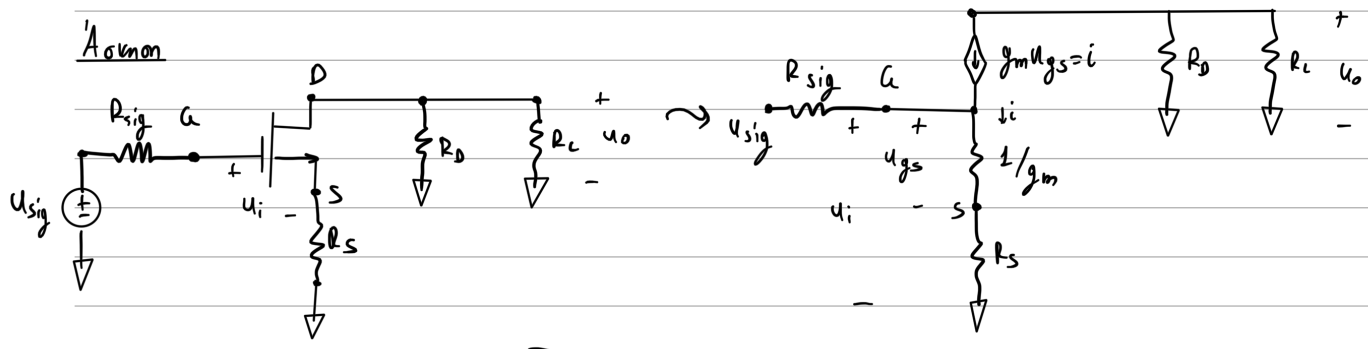


Ενισχυτής Κοινής Πηγής (CS)



$$\frac{u_o}{u_{sig}} = \frac{-g_m u_{GS} (R_o // R_L)}{u_{sig}} \xrightarrow{u_{GS} = u_i = u_{sig}} \frac{u_o}{u_{sig}} = -g_m (R_o // R_L)$$

Ασκήση



$$u_o = -g_m u_{GS} (R_o // R_L) = -i (R_o // R_L)$$

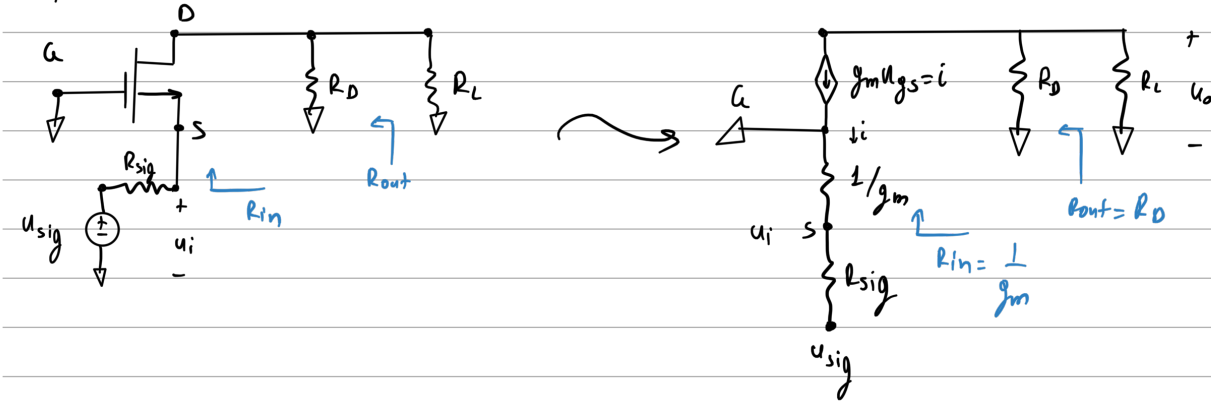
$$i = \frac{u_i}{\frac{1}{g_m} + R_S}$$

$$\xrightarrow{u_i = u_{sig}} \frac{u_o}{u_{sig}} = - \frac{R_o // R_L}{\frac{1}{g_m} + R_S}$$

$$A_{V_{u \rightarrow o}} = \frac{u_o}{u_{sig}} = - \frac{R_o \lambda_o}{R_o \lambda_s}$$

Ενισχυτής Κοινής Πύλης (CA)

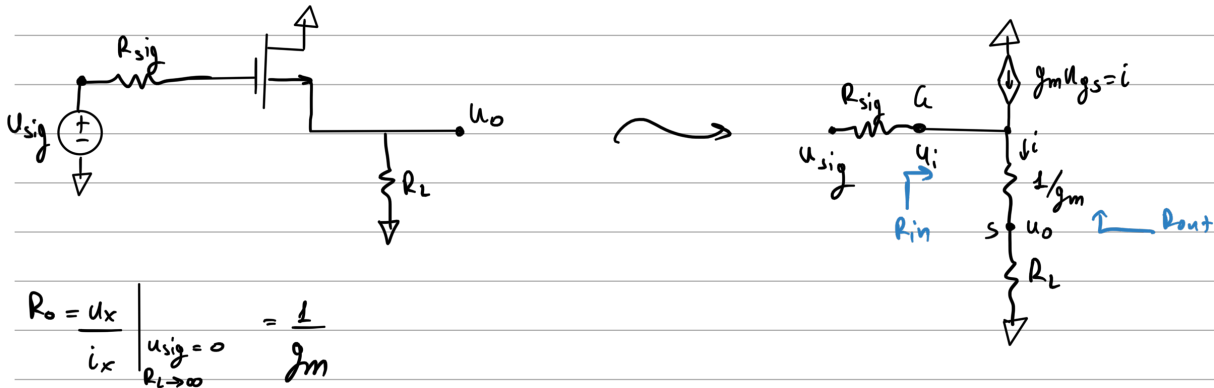
~ αντιστοίχος του CB



$$\begin{aligned}
 u_o &= -i (R_D \parallel R_L) \\
 i &= \frac{-u_i}{\frac{1}{g_m}} \quad \rightarrow \quad u_o = \frac{u_i (R_D \parallel R_L)}{\frac{1}{g_m}} \quad \rightarrow \quad \frac{u_o}{u_i} = g_m (R_D \parallel R_L) \\
 \frac{u_o}{u_i} &= \frac{\frac{1}{g_m}}{\frac{1}{g_m} + R_{sig}} u_{sig} \quad \rightarrow \quad \frac{u_o}{u_{sig}} = \frac{R_D \parallel R_L}{R_{sig} + \frac{1}{g_m}} \\
 A_{v_{s \rightarrow D}} &= \frac{u_o}{u_{sig}} = \frac{R_{o\lambda, D}}{R_{o\lambda, s}}
 \end{aligned}$$

Ενισχυτής Κοινής Υποδοχής (CD) ή Ακολουθούσης Τηξης

~ αντιστοίχος του CC (ή ακαθ. εκπομπά)



$$R_o = \frac{u_x}{i_x} \bigg|_{u_{sig}=0, R_L \rightarrow \infty} = \frac{1}{g_m}$$

$$R_{in} = \infty, u_{sg} = u_i, u_o = \frac{R_L}{R_L + R_{sig}} u_{sig} \quad \rightarrow \quad \frac{u_o}{u_{sig}} = \frac{R_L}{R_L + \frac{1}{g_m}} < 1$$

$$\text{Επειδή } \frac{1}{g_m} \ll R_L \quad \rightsquigarrow \quad \frac{u_o}{u_{sig}} \simeq 1$$

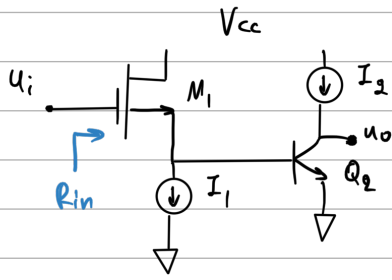
$$\begin{aligned}
 R_{in} &= \infty \\
 R_o &= \frac{1}{g_m} \ll 1 \\
 \frac{u_o}{u_{sig}} &\simeq 1
 \end{aligned}
 \quad \rightarrow \quad \text{απομονωτής τάσης (buffer)}$$

στάδιο εξόδου σε ενισχυτή πολλών σταδίων

Άσκηση: Ενισχυτής CD-CE

$$V_T = 25 \text{ mV}, \beta_2 = 100, k_{n1} = 8 \text{ mA/V}^2$$

$$I_1 = I_2 = 1 \text{ mA}$$

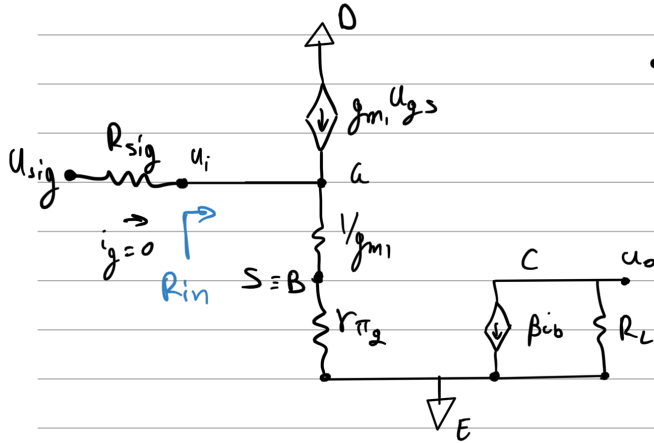


Αντίστροφο παρ. σήμα στο M_1 , παρ. Early στα M_1, Q_2 .

a) $R_{in} = ?$, $R_{sig} = 4 \text{ k}\Omega$

β) $u_o/u_{sig} = ?$, $R_{sig} = 4 \text{ k}\Omega$

και αν $R_{sig} = 400 \text{ k}\Omega$?



• $R_{in} = \infty$, $\forall R_{sig}$

• $u_o = -\beta i_b R_L$

• $i_b = \frac{u_i}{\frac{1}{g_{m1}} + r_{\pi 2}}$

• $u_i = u_{sig}$

$$\frac{u_o}{u_{sig}} = \frac{-\beta R_L}{\frac{1}{g_{m1}} + r_{\pi 2}} \approx R_{sig} = -145,5 \text{ V/V}$$

$$g_{m1} = \sqrt{2k_n I_0} = 4 \text{ mS}, \quad g_{m2} = \frac{I_C}{V_T} = 40 \text{ mS}, \quad r_{\pi 2} = \frac{\beta}{g_{m2}} = 2,5 \text{ k}\Omega$$